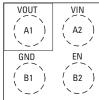
## 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control





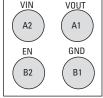


# **Pinout Designation**





Top View



**Bottom View** 

#### **Description**

The LQ05022QCS4 is an ultimated efficient, 2 A rated integrated load switch with slew rate control. Its outstanding performance in efficiency makes this an ideal solution for applications like IoT, mobile and wearable.

This remarkable device incorporates cutting-edge technology that achieves industry-leading performance in terms of the lowest quiescent current ( $I_0$ ), and shutdown current ( $I_{sp}$ ). The low  $I_0$  and I<sub>sp</sub> solutions empower designers to curtail parasitic leakage current, enhance system efficiency, and extend battery lifespan.

The integration of slew rate control within the LQ05022QCS4 serves as a critical enhancement to system reliability, effectively mitigating voltage swings on the bus during switching events. In situations where uncontrolled switches might otherwise generate substantial inrush currents, leading to voltage droop and potential bus reset events, the slew rate control functions to confine inrush current during activation, thereby minimizing the voltage droop.

The LQ05022QCS4 load switch device is designed in a chip scale package of 0.97 mm x 0.97 mm x 0.55 mm with 4 bumps and 0.5 mm pitch and support an extensive input voltage range, enhancing both the operational lifespan and the resilience of the system. Additionally, this single device can serve in various voltage rail applications, streamlining inventory management and lowering operational expenses.

#### **Pin Description**

Pin#	Pin Name	Description
A1	V <sub>OUT</sub>	Switch output
A2	V <sub>IN</sub>	Switch input. Supply voltage for IC
B1	GND	Ground
B2	EN	Enable to control the switch

#### **Features and Benefits**

- Ultra-low I<sub>o</sub>: 7 nA Typ @ 5.5
- Ultra-low I<sub>SD</sub>: 28 nA Typ @ 5.5 V<sub>INI</sub>
- Low  $R_{ON} = 31 \text{ m}\Omega \text{ Typ } @ 5.5$
- $I_{OUT}$  max = 2.0 A
- Wide input range: 1.1 V to 5.5 V, 6 Vabs max
- Controlled rise time: 335 µs at 3.3 V<sub>IN</sub>
- Internal EN pull-down resistor
- Integrated output discharge switch
- Ultra-small: 4 bumps in a 0.97 mm x 0.97 mm x 0.55 mm **WLCSP**

### **Applications**

- Mobile devices
- Data storage, SSD
- IoT devices

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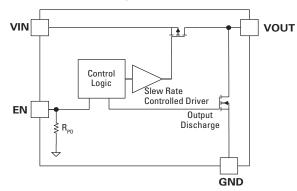
- Wearables
- Low power subsystems



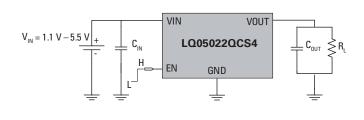
# L0050220CS4

# 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

### **Functional Block Diagram**



## **Typical Applications**



### **Absolute Maximum Rating**

Symbol	Par	Min	Max	Unit	
$V_{\rm IN}, V_{\rm OUT}, V_{\rm EN}$	Each Pin Volta	-0.3	6	V	
I <sub>out</sub>	Maximum Contir		2	А	
$P_{D}$	Power Dissipa		1.2	W	
T <sub>STG</sub>	Storage June	-65	150	°C	
$T_{J}$	Maximum Jur		150	°C	
$\theta_{\sf JA}$	Thermal Resistance		85	°C/W	
ESD	FI	Human Body Model, JESD22-A114	6		kV
	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	2		kV

**Note:** Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

### **Recommend Operating Conditions**

Symbol	Parameter	Min	Max	Unit
$V_{IN}$	Supply Voltage	1.1	5.5	V
T <sub>A</sub>	Ambient Operating Temperature	-40	85	°C

**Note:** The device is not guaranteed to function outside of the recommended operating conditions.



# 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

## **Electrical Characteristics** (Values are at $V_{IN}$ = 3.3 V and $T_A$ = 25 °C unless otherwise noted.)

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
Basic Operati	on						
V <sub>IN</sub>	Supply Voltage			1.1		5.5	V
		$V_{IN} = V_{EN} = 5.5  V_{EN}$	V, I <sub>OUT</sub> = 0 mA		570		nA
Ι <sub>α</sub>	Quiescent Current	$V_{IN} = V_{EN} = 5.5 V$	$I_{OUT} = 0 \text{ mA}^1$		7	70	nA
		$V_{IN} = V_{EN} = 5.5 \text{ V, I}_{OUT} =$	0 mA, T <sub>A</sub> = 85 °C <sup>1,5</sup>		12		nA
		EN = Disable, I <sub>OUT</sub> =	0 mA, V <sub>IN</sub> = 1.1 V		5		nA
		EN = Disable, I <sub>OUT</sub> =	$0 \text{ mA, V}_{IN} = 1.8 \text{ V}$		6		nA
		EN = Disable, I <sub>OUT</sub> =	0 mA, $V_{IN} = 3.3 \text{ V}$		9	35	nA
I <sub>SD</sub>		EN = Disable, I <sub>OUT</sub> =	0 mA, V <sub>IN</sub> = 4.5 V		13		nA
		EN = Disable, I <sub>OUT</sub> =	0 mA, V <sub>IN</sub> = 5.5 V		28	100	nA
		EN = Disable, I <sub>OUT</sub> = 0 mA	$V_{IN} = 5.5 \ V, T_{A} = 55 \ ^{\circ}C^{5}$		200		nA
		EN = Disable, I <sub>OUT</sub> = 0 mA	$v_{IN} = 5.5 \text{ V}, T_A = 85 ^{\circ}\text{C}^{5}$		1		μΑ
	On-Resistance	$V_{IN} = 5.5 \text{ V}, I_{OLIT} = 500 \text{ mA}$	T <sub>A</sub> = 25 °C		31	34	mΩ
		$V_{IN} = 5.5 \text{ V}, I_{OUT} = 500 \text{ IIIA}$	T <sub>A</sub> = 85 °C		36		mΩ
R		VI <sub>IN</sub> = 3.3 V, I <sub>OUT</sub> = 500 mA	$T_A = 25  ^{\circ}C$		36	41	mΩ
$R_{on}$			$T_A = 85  ^{\circ}C^5$		43		mΩ
		$V_{IN} = 1.8 \text{ V}, I_{OUT} = 300 \text{ mA}$	$T_A = 25  ^{\circ}C$		52	60	mΩ
		$V_{IN} = 1.1 \text{ V, } I_{OUT} = 100 \text{ mA}$	$T_A = 25  ^{\circ}C$		95	120	mΩ
R <sub>DSC</sub>	Output Discharge Resistance	$E_{N} = Low , I_{FOF}$	RCE = 10 mA	70	85	100	Ω
V <sub>IH</sub>	EN Input Logic High Voltage	V <sub>IN</sub> = 1.1 V - 1.8 V		0.9			V
V IH	Liv input Logic riigir voitago	$V_{IN} = 1.8 V$	1.2			V	
V <sub>IL</sub>	EN Input Logic Low Voltage	V <sub>IN</sub> = 1.1 V - 1.8 V				0.3	V
V IL	Liv input Logio Low voitage	V <sub>IN</sub> = 1.8 V			0.4	V	
R <sub>EN</sub>	EN Internal resistance	Internal Pull-down Resistance			9.5		ΜΩ
I <sub>EN</sub>	EN Current	E <sub>N</sub> = 5.5 V				1	μΑ
Switching Ch	aracteristics						
t <sub>dON</sub>	Turn-On Delay <sup>2</sup>	B = 150 O C	= 0.1 µF		210		μs
t <sub>R</sub>	V <sub>OUT</sub> Rise Time <sup>2</sup>	11 = 100 12, 0	$R_{L} = 150 \Omega, C_{OUT} = 0.1 \mu F$		335		μs
t <sub>dON</sub>	Turn-On Delay <sup>2.5</sup>	R = 500 O C	= 0.1 uF		220		μs
t <sub>R</sub>	V <sub>OUT</sub> Rise Time <sup>2.5</sup>	$R_{L} = 500 \Omega, C_{OUT} = 0.1 \mu F$			330		μs
t <sub>dOFF</sub>	Turn-Off Delay <sup>3,4,5</sup>	R = 10 0 C	= 0.1 uF		0.38		μs
t <sub>F</sub>	V <sub>out</sub> Fall Time <sup>3.5</sup>	11 <sub>L</sub> = 10 12, 0 <sub>0</sub>	$R_L = 10 Ω, C_{OUT} = 0.1 μF$		1.30		μs
t <sub>dOFF</sub>	Turn-Off Delay <sup>3,4,5</sup>	B = 500 0 C	$R_L = 500 \Omega$ , $C_{OUT} = 0.1 \mu F$		0.9		μs
$t_{\scriptscriptstyleF}$	V <sub>out</sub> Fall Time <sup>3.4.5</sup>	11 <sub>L</sub> = 300 12, C <sub>OUT</sub> = 0.1 μ1			16		μs

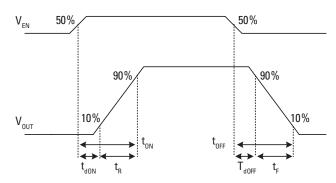
### Notes:

- 1.  $I_{\rm Q}$  does not include enable pull down current through the pull-down resistor RPD.

- 2. t<sub>oN</sub> = td<sub>oN</sub> + t<sub>R</sub>
  3. t<sub>oFF</sub> = td<sub>oFF</sub> + t<sub>F</sub>
  4. Output discharge path is enabled during off.
- 5. By design; characterized, not production tested.



### **Timing Waveforms**



### **Typical Performance Characteristics**

Figure 1 - On-Resistance vs. Supply Voltage

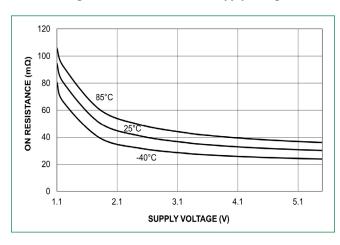


Figure 2 - On-Resistance vs. Temperature

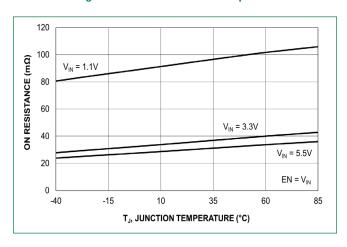


Figure 3 - Quiescent Current vs. Supply Voltage

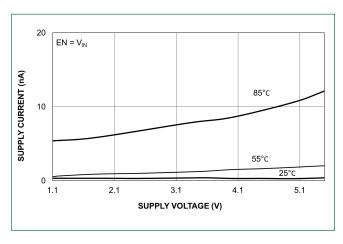


Figure 4 - Quiescent Current vs. Temperature

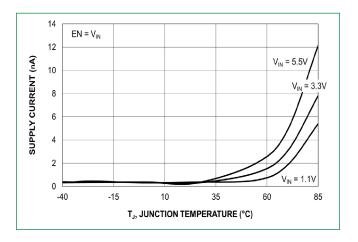




Figure 5 - Shut Down Current vs. Input Voltage

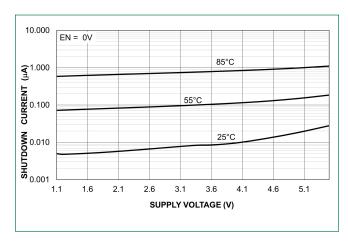


Figure 6 - Shutdown Current vs. Temperature

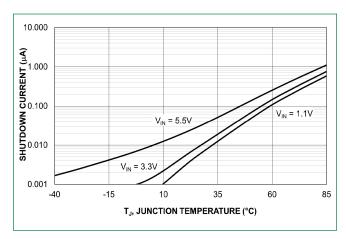


Figure 7 - EN Input Logic High Threshold

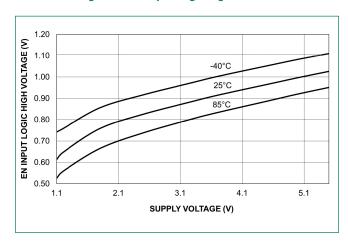


Figure 8 - EN Input Logic High Threshold Vs. Temperature

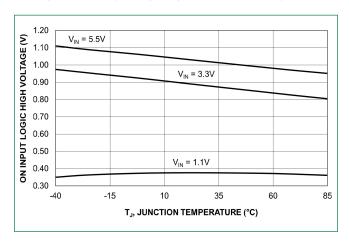


Figure 9 - EN Input Logic Low Threshold

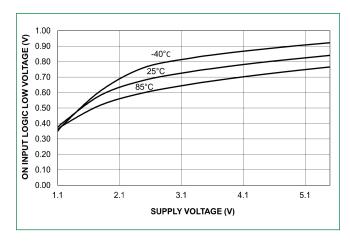
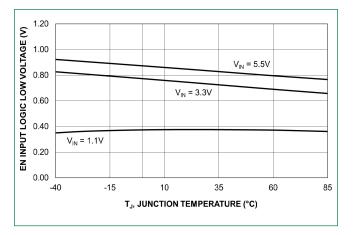


Figure 10 - EN Input Logic Low Threshold Vs. Temperature





# 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

Figure 11 - V<sub>OUT</sub> Rise Time vs. Temperature

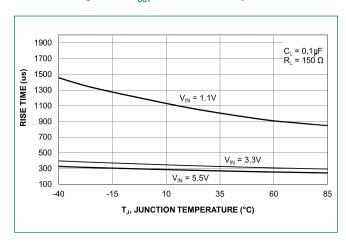


Figure 12 - Turn-On Delay Time vs. Temperature

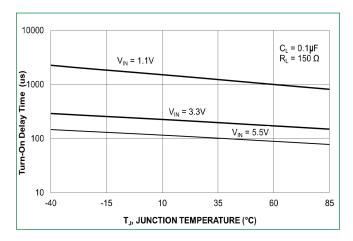


Figure 13 - Turn-On Response  $V_{_{IN}}$  = 3.3 V,  $C_{_{IN}}$  = 1.0  $\mu\text{F},\,C_{_{OUT}}$  = 0.1  $\mu\text{F},\,R_{_{L}}$  = 10  $\Omega$ 

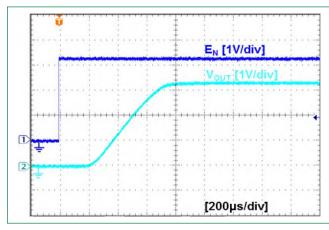


Figure 14 - Turn-On Response V  $_{_{IN}}$  = 3.3 V, C  $_{_{IN}}$  = 1.0  $\mu\text{F, C}_{_{OUT}}$  = 0.1  $\mu\text{F, R}_{_{L}}$  = 500  $\Omega$ 

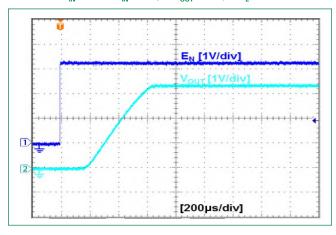


Figure 15 - Turn-Off Response, Output Discharge V  $_{\text{IN}}\!=\!3.3$  V, C  $_{\text{IN}}\!=\!1.0$   $\mu\text{F},$  C  $_{\text{OUT}}\!=0.1$   $\mu\text{F},$  R  $_{\text{L}}$  = 10  $\Omega$ 

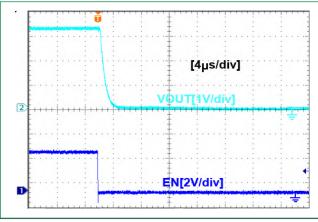
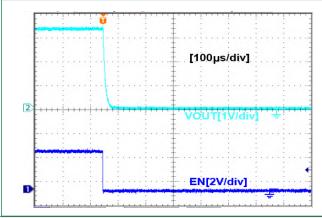


Figure 16 - Turn-Off Response, Output Discharge  $V_{IN}$ =3.3 V,  $C_{IN}$ =1.0  $\mu$ F,  $C_{OUT}$ = 0.1  $\mu$ F,  $R_L$  = 500  $\Omega$ 



# 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

### **Application Information**

The LQ05022QCS4 is a highly efficient integrated load switch with a 2 A capacity. It allows a fixed slew rate control to limit inrush current when activated. This device works with a wide input voltage range, from 1.1 V to 5.5 V, and has minimal on-resistance to reduce power loss. When it is off, it has very low leakage current, saving power resources. It is in a chip scale size package at 0.97 mm x 0.97 mm x 0.55 mm with 4 bumps at a 0.5 mm pitch make it ideal for efficient manufacturing in the space-saving required applications.

#### **Input Capacitor**

Although this is not required to have an input capacitor. Suggest to use a 0.1 µF capacitor positioned near the VIN pin to address voltage fluctuations on the input power rail that may occur as a result of transient inrush current during startup. To reduce the extent of the input voltage drop, suggest to use a higher input capacitor value.

#### **Output Capacitor**

An output capacitor is not mandatory for the LQ05022QCS4. Nevertheless, it is advisable to employ an output capacitor to minimize voltage undershoot on the output pin during switch-off.

Voltage undershoot may arise due to parasitic inductance from board traces or deliberate load inductances. In the presence of load inductances, utilizing an output capacitor can enhance output voltage stability and overall system reliability. Position the  $C_{\text{OUT}}$  capacitor in close proximity to the  $V_{\text{OUT}}$  and GND pins.

#### EN pin

The LQ05022QCS4 can be turned on by setting the EN pin to a high level. Be aware that there is an internal pull-down resistor in EN pin which can pull the primary switch to "off state" as long as no EN signal from an external controller is applied.

#### **Output Discharge Function**

The device incorporates an internal discharge N-channel FET switch located at the VOUT pin. When the EN signal switches the primary power FET to an off state, the N-channel switch activates to rapidly discharge the output capacitor.

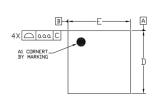
#### **Board Layout**

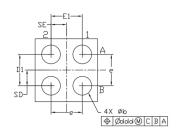
To minimize the impact of parasitic inductance, it is advisable to keep all traces as short as possible. Using wider traces for  $V_{IN'}$ ,  $V_{OUT'}$  and GND is recommended to mitigate parasitic effects during dynamic operations and enhance thermal efficiency under high load currents.

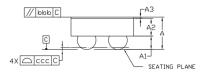


# 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

### **Dimensions**

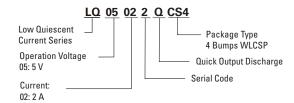






Dimension	Millimeters							
Dilliension	Min	Nom	Max					
Α	0.500	0.550	0.600					
A1	0.225	0.250	0.275					
A2	0.225	0.275	0.300					
А3	0.020	0.025	0.030					
D	0.960	0.970	0.985					
Е	0.960	0.970	0.985					
D1	0.450	0.500	0.550					
E1	0.450	0.500	0.550					
b	0.260	0.310	0.360					
е	0.500 BSC							
SD	0.250 BSC							
SE		0.250 BSC						
Tol. of Form & Position								
aaa	0.100							
bbb	0.100							
CCC		0.050						
ddd		0.050						

### **Part Numbering**



### **Part Marking**



Pin 1 mark

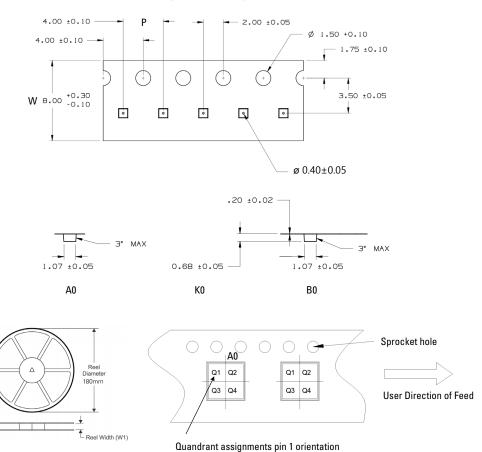
BC = Device Code

XX = Wafer Lot Run Code

xx = Assembly Lot Run Code

A = Assembly Code

### **Carrier Tape & Reel Specification**



Device	Package	Pins	SPQ	Reel Diameter	Reel Width W1	A0	В0	КО	Р	W	Pin1
LQ05022QCS4	4 Bumps WLCSP	4	3000	180	9	1.07	1.07	0.68	4	8	Q1

Dimensions are in millimeters

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